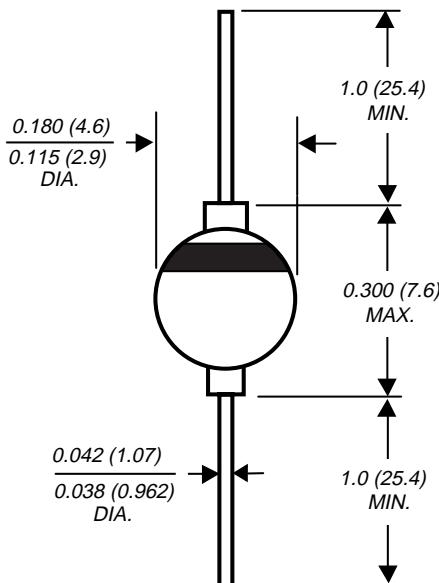

**Case Style G4**

*Dimensions in inches and (millimeters)*
*\* Brazed-lead assembly is covered by Patent No. 3,930,306*
*Patented\**

## Glass Passivated Ultrafast Rectifier

**Reverse Voltage** 50 to 200V

**Forward Current** 3.0A

### Features

- High temperature metallurgically bonded construction
- Cavity-free glass passivated junction
- Superfast recovery time for high efficiency
- Low forward voltage, high current capability
- Capable of meeting environmental standards of MIL-S-19500
- Hermetically sealed package
- Low leakage current
- High surge current capability
- High temperature soldering guaranteed: 350°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

### Mechanical Data

**Case:** Solid glass body

**Terminals:** Plated axial leads, solderable per MIL-STD-750, Method 2026

**Polarity:** Color band denotes cathode end

**Mounting Position:** Any

**Weight:** 0.037 ounce, 1.04 grams

### Maximum Ratings and Thermal Characteristics

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Parameter	Symbol	FE3A	FE3B	FE3	FE3D	Unit
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	150	200	V
Maximum RMS voltage	$V_{RMS}$	35	70	105	140	V
Maximum DC blocking voltage	$V_{DC}$	50	100	150	200	V
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_A = 55^\circ\text{C}$	$I_{F(AV)}$	3.0				A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	125				A
Typical thermal resistance (Note 1,2)	$R_{\theta JA}$ $R_{\theta JL}$	55 20				$^\circ\text{C/W}$
Operating junction and storage temperature range	$T_J, T_{STG}$	−65 to +175				$^\circ\text{C}$

### Electrical Characteristics

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Parameter	Symbol	FE3A	FE3B	FE3	FE3D	Unit
Maximum instantaneous forward voltage at 3.0A	$V_F$	0.95				V
Maximum DC reverse current $T_A = 25^\circ\text{C}$ at rated DC blocking voltage $T_A = 100^\circ\text{C}$	$I_R$	5.0 50				$\mu\text{A}$
Maximum reverse recovery time at $I_F = 0.5\text{A}$ , $I_R = 1.0\text{A}$ , $I_{rr} = 0.25\text{A}$	$t_{rr}$	35				ns
Typical junction capacitance at 4V, 1MHz	$C_J$	100				pF

**Notes:**

- (1) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length and mounted on P.C.B. with 0.5 x 0.5 (12 x 12mm) copper pads.
- (2) Thermal resistance from junction to lead at 0.375" (9.5mm) lead length with both leads attached to heatsinks.

# Glass Passivated Ultrafast Rectifier

## Ratings and Characteristic Curves ( $T_A=25^\circ\text{C}$ unless otherwise noted.)

FIG. 1 - MAXIMUM FORWARD CURRENT DERATING

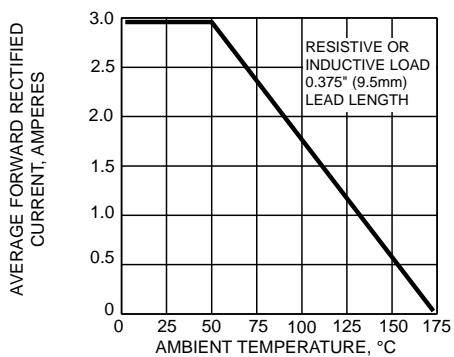


FIG. 2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

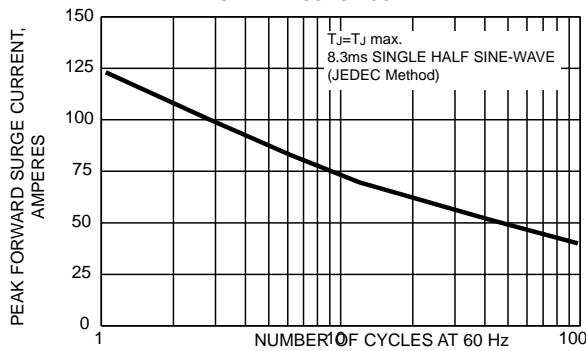


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

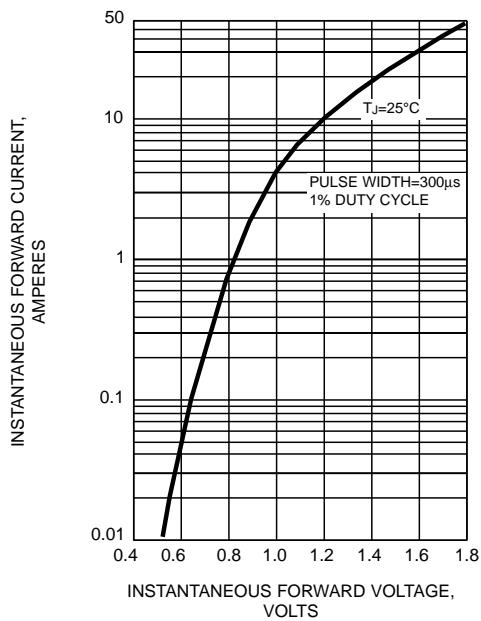


FIG. 4 - TYPICAL REVERSE LEAKAGE CHARACTERISTICS

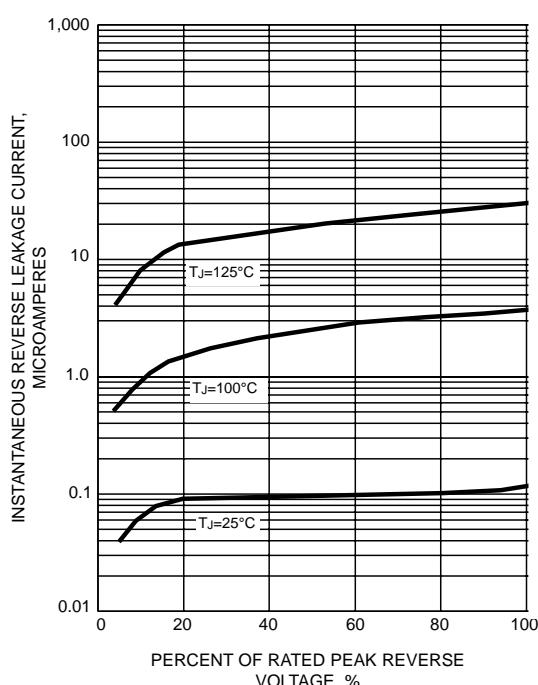


FIG. 5 - TYPICAL JUNCTION CAPACITANCE

